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Attorney's Docket No.: 10559-587001 / P12768

GP/2812

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Been-Yih Jin et al.

Art Unit : 2812

Serial No. : 10/081,992

Examiner : Unknown

Filed : February 21, 2002

Title : NON-SILICON SEMICONDUCTOR AND HIGH-K GATE DIELECTRIC
METAL OXIDE SEMICONDUCTOR FIELD EFFECT TRANSISTORS

Commissioner for Patents
Washington, D.C. 20231

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INFORMATION DISCLOSURE STATEMENT

Applicants submit the references listed on the attached form PTO-1449, copies of which are enclosed.

This statement is being filed before the receipt of a first Office action on the merits.

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Respectfully submitted,

Date: August 8, 2002

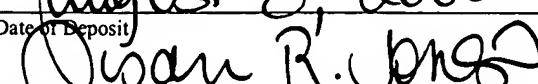
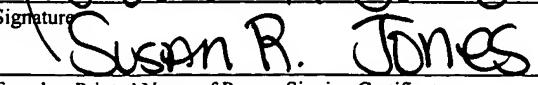

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Substitute Form PTO-1449 (Modified)		Department of Commerce Patent and Trademark Office	Attorney's Docket No. 10559-587001	Application No. 10/081,992
Information Disclosure Statement by Applicant (Use several sheets if necessary)		Applicant Been-Yih Jin et al.		
		Filing Date February 21, 2002	Group Art Unit 2812	
(37 CFR §1.98(b))				

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AA							
	AB							
	AC							
	AD							
	AE							

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document	
		Author	Title, Date, and Place of Publication
	AF	Chau et al.	International Electron Devices Meeting 2000, San Francisco, CA, December 10-13, 2000.
	AG	Ghani et al.	Symposium on VLSI Technology Digest of Technical Papers, Honolulu, HI, June 13-15, 2000.
	AH	Hubbard et al.	"Thermodynamic stability of binary oxides in contact with silicon" J. Mater. Res., Vol. 11, No. 11, Nov. 1996.

Examiner Signature

Date Considered

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.